

HITJ0303MP

–30V, –3.3A, 68mΩmax.
Silicon P Channel MOS FET
Power Switching

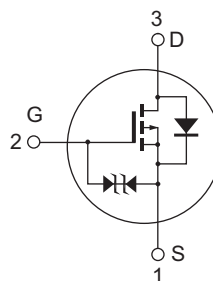
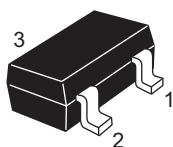
R07DS0478EJ0200
Rev.2.00
May 09, 2013

Features

- Low on-resistance
 $R_{DS(on)} = 54 \text{ m}\Omega \text{ typ}$ ($V_{GS} = -10 \text{ V}$, $I_D = -1.6 \text{ A}$)
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline

RENESAS Package code: PLSP0003ZB-A
(Package name: MPAK)



1. Source
2. Gate
3. Drain

Note: Marking is "PV".

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	–30	V
Gate to source voltage	V_{GSS}	+10 / –20	V
Drain current	I_D	–3.3	A
Drain peak current	$I_{D(Pulse)}$ ^{Note1}	–5	A
Body - drain diode reverse drain current	I_{DR}	–3.3	A
Channel dissipation	P_{ch} ^{Note2}	0.8	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	–55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. When using the glass epoxy board (FR-4: $40 \times 40 \times 1 \text{ mm}$)

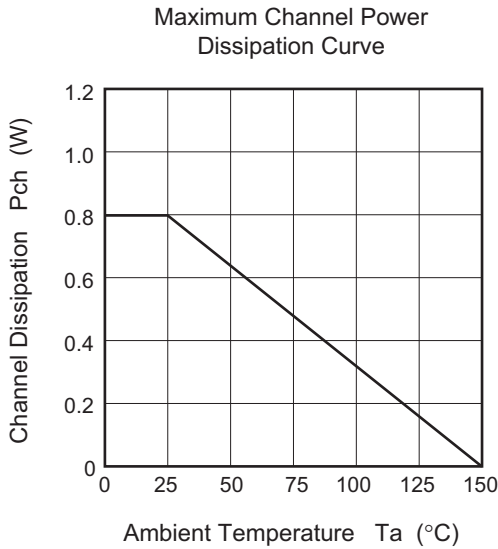
Electrical Characteristics

(Ta = 25°C)

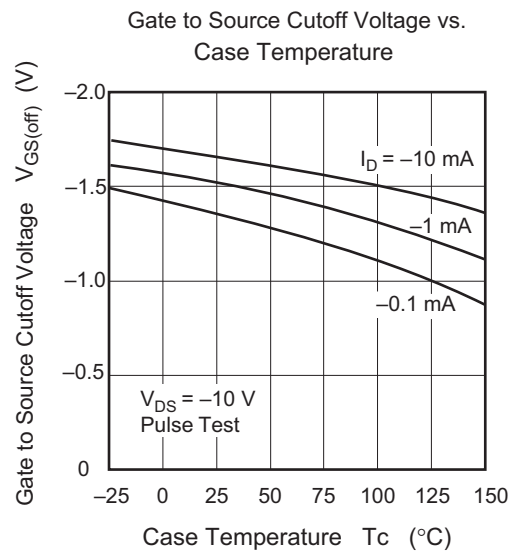
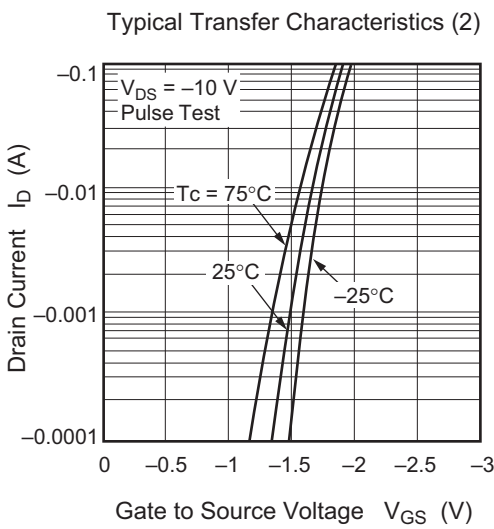
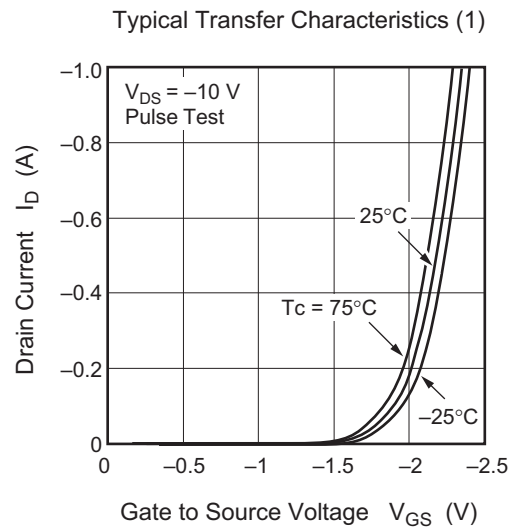
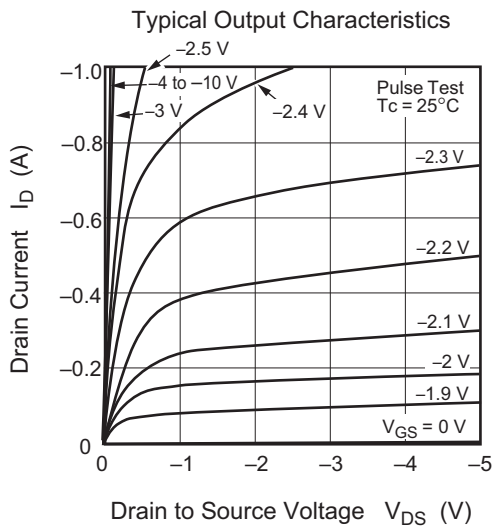
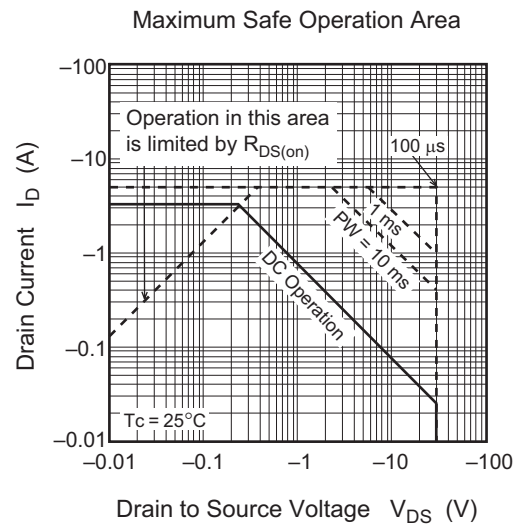
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-30	—	—	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+10	—	—	V	$I_G = +100 \text{ } \mu\text{A}, V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-20	—	—	V	$I_G = -100 \text{ } \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	+10	μA	$V_{GS} = +8 \text{ V}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	-10	μA	$V_{GS} = -16 \text{ V}, V_{DS} = 0$
Drain to source leak current	I_{DSS}	—	—	-1	μA	$V_{DS} = -30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	—	-2.0	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Drain to source on state resistance	$R_{DS(on)}$	—	54	68	$\text{m}\Omega$	$I_D = -1.6 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note3}}$
	$R_{DS(on)}$	—	76	107	$\text{m}\Omega$	$I_D = -1.6 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	$ y_{fs} $	2.5	4.2	—	S	$I_D = -1.6 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$
Input capacitance	C_{iss}	—	625	—	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0,$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	111	—	pF	
Reverse transfer capacitance	C_{rss}	—	83	—	pF	
Turn - on delay time	$t_{d(on)}$	—	18	—	ns	$I_D = -1 \text{ A}, V_{GS} = -10 \text{ V},$ $R_L = 6.6 \text{ } \Omega, R_g = 4.7 \text{ } \Omega$
Rise time	t_r	—	29	—	ns	
Turn - off delay time	$t_{d(off)}$	—	47	—	ns	
Fall time	t_f	—	5.7	—	ns	
Total gate charge	Q_g	—	12	—	nC	$V_{DD} = -10 \text{ V}, V_{GS} = -10 \text{ V},$ $I_D = -3.3 \text{ A}$
Gate to source charge	Q_{gs}	—	1.5	—	nC	
Gate to drain charge	Q_{gd}	—	2.9	—	nC	
Body - drain diode forward voltage	V_{DF}	—	-0.9	—	V	$I_F = -1.5 \text{ A}, V_{GS} = 0^{\text{Note3}}$

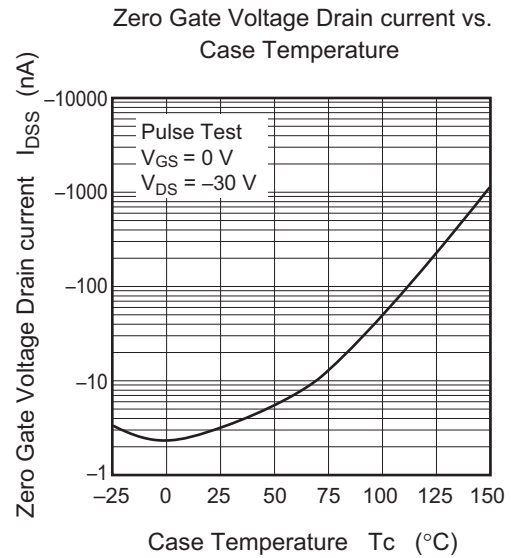
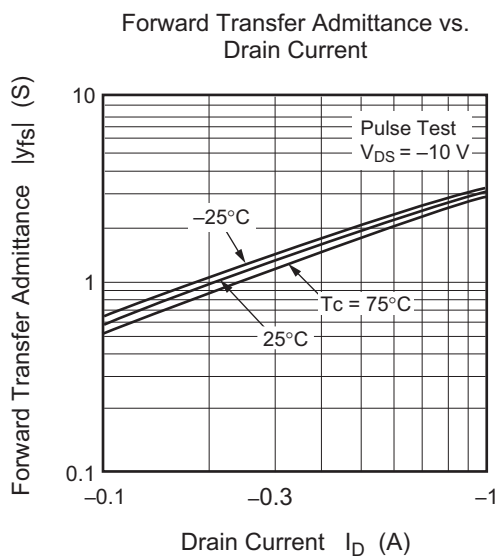
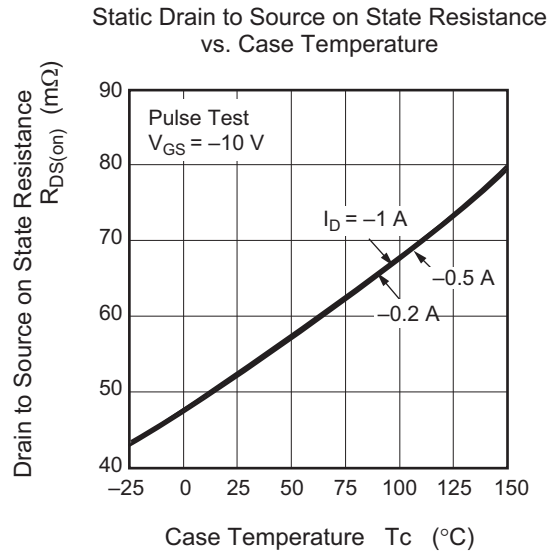
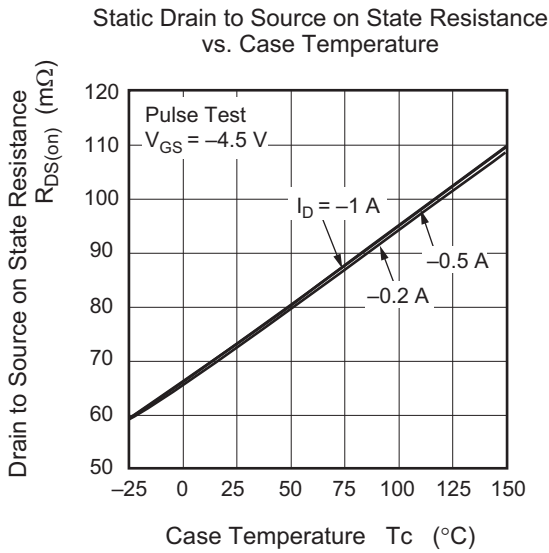
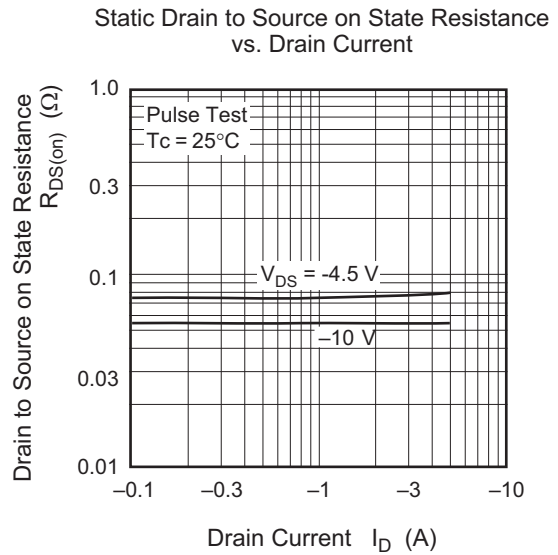
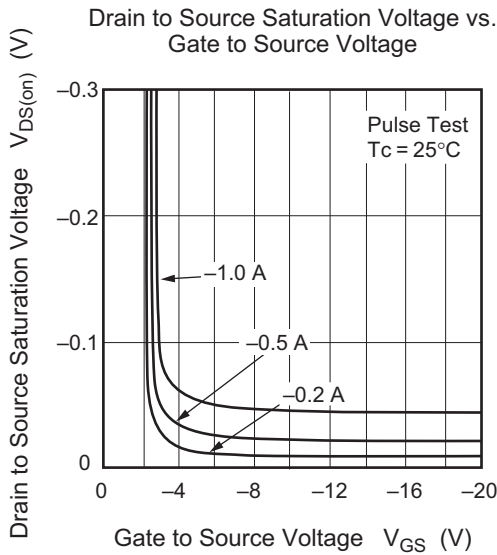
Notes: 3. Pulse test

Main Characteristics

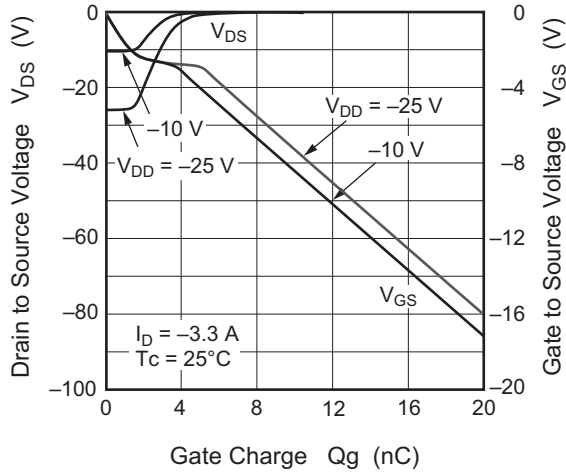


*When using the glass epoxy board (FR-4: 40 × 40 × 1 mm)

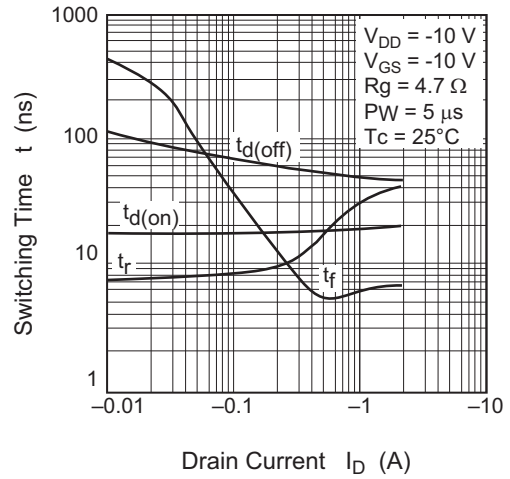




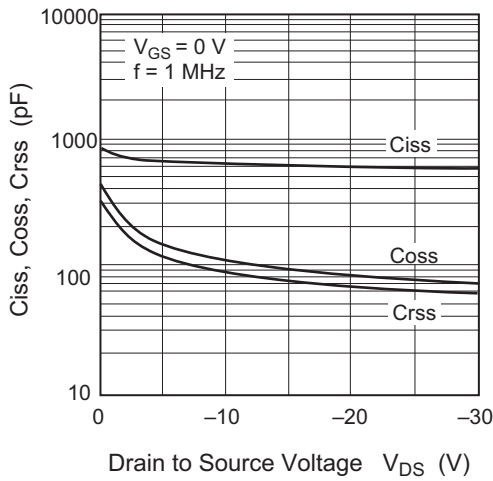
Dynamic Input Characteristics



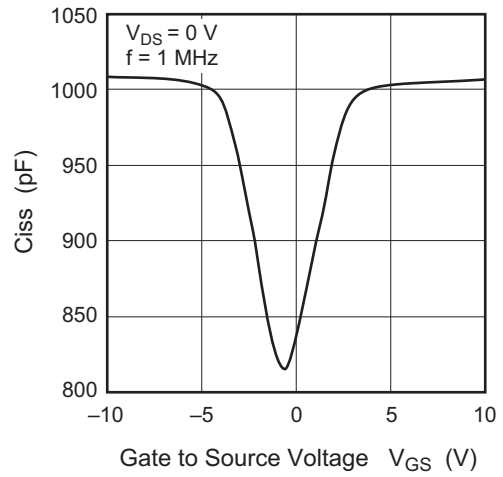
Switching Characteristics



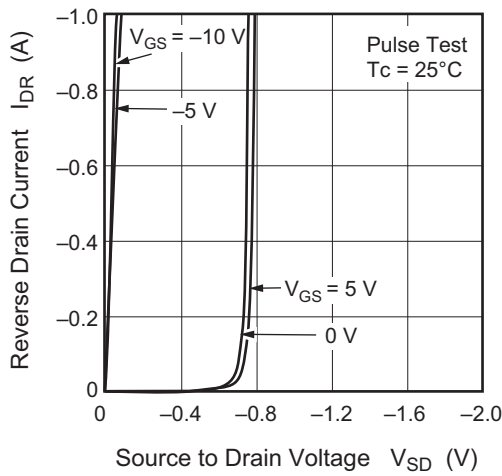
Typical Capacitance vs. Drain to Source Voltage



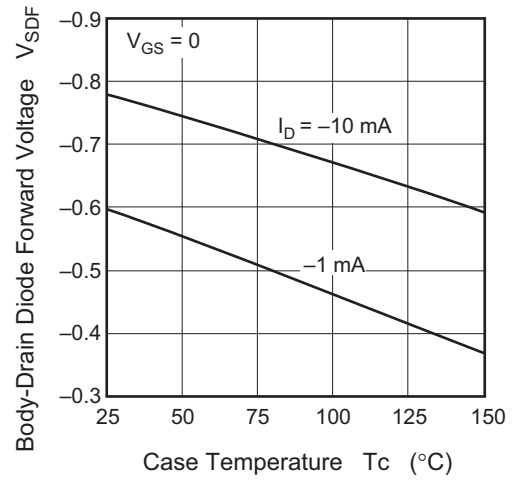
Input Capacitance vs. Gate to Source Voltage



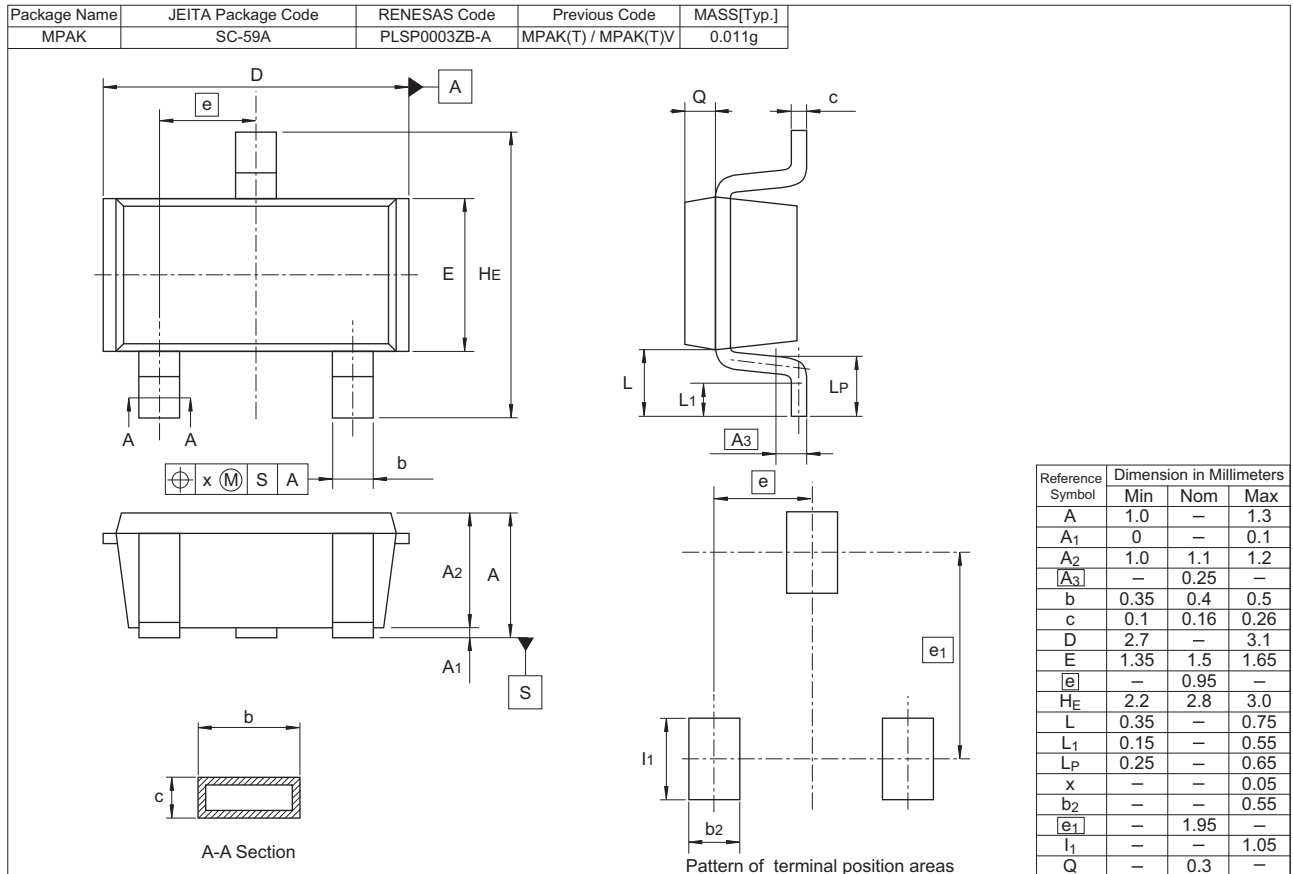
Reverse Drain Current vs. Source to Drain Voltage



Body-Drain Diode Forward Voltage vs. Case Temperature



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
HITJ0303MPTL-HQ	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

Note: This product is designed for consumer use and not for automotive.

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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-3390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Laviel' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141